	Туре	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Err
1	BRS	L1	1235	circuitry		2005/06/1 0 12:10			
2	BRS	L2		low voltag differential signaling		2005/06/1 0 12:10			
3	BRS	L3	1165	(low voltag differential signaling or lvds) and L1	US- PGPUB ; USPAT ; USOCR	2005/06/1 0 12:12			
4	BRS	L4	38711	(synchronous semiconductor memory device) and (signal generating circuit) and (latch or (flip adj flop) or gate) and (transmission gate)	Ι.	2005/06/1 0 12:13			
5	BRS	L5	713	(D adj flip adj flop)and clock and enable and "327".clas.	US- PGPUB ; USPAT ; USOCR	2005/06/1 0 12:14			
6	BRS	L6	41381 3	(d (latch or (flip adj flop) or gate)) and (transmission and gate) and multiplexor and shift register	;	2005/06/1 0 12:14			
7	BRS	L11	466	synchronous and semiconductor and memory and device and signal and boosting	US- PGPUB; USPAT; USOCR	2005/06/1 0 12:18			
8	BRS	L12	61550	amplifier and L6	US- PGPUB ; USPAT ; USOCR	2005/06/1 0 12:19			